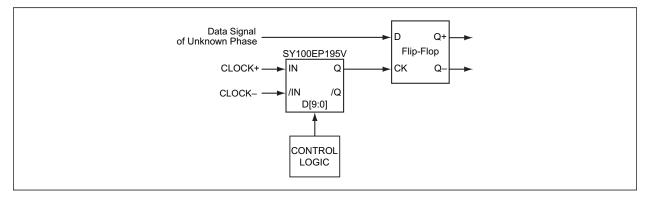
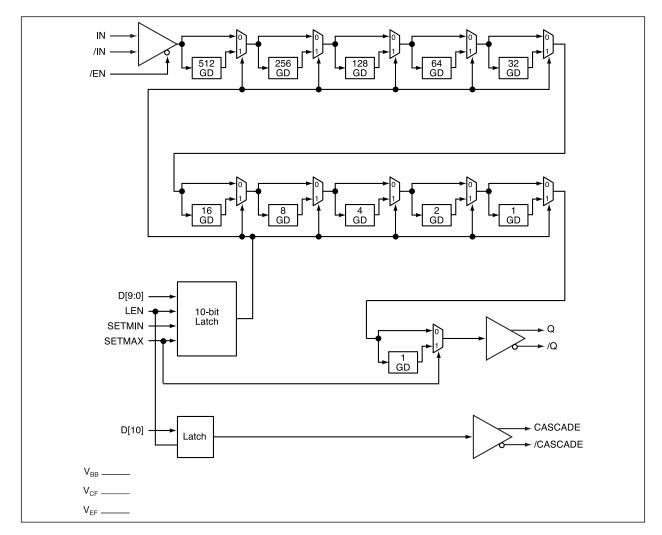
Typical Application Circuit



Functional Block Diagram



DS20006194A-page 2

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V _{CC}) PECL Mode (V _{EE} = 0V) Supply Voltage (V _{EE}) NECL Mode (V _{CC} = 0V)	
Any Input Voltage (V _{IN})	
PECL Mode	–0.5V to V _{CC} + 0.5V
NECL Mode	+0.5V to V _{EE} – 0.5V
ECL Output Current (I _{OUT})	
Continuous	50 mA
Surge	100 mA
I _{BB} Sink/Source Current	±0.5 mA
ESD Rating (Note 1)	

Operating Ratings ‡

Supply Voltage (V _{CC}) PECL Mode (V _{EE} = 0V)	+3.0V to +5.5V
Supply Voltage (V _{EE}) NECL Mode (V _{CC} = 0V)	–3.0V to –5.5V

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions recommended.

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DC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: $T_A = -40^{\circ}C$ to +85°C, unless otherwise stated.								
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions		
	N/	3.0	3.3	3.6	V			
Power Supply Voltage (PECL)	V _{CC}	4.5	5.0	5.5		—		
Dower Supply Voltage (NECL)	V	-3.6	-3.3	-3.0	V			
Power Supply Voltage (NECL)	V _{EE}	-5.5	-5.0	-4.5		—		
Power Supply Current (Note 1)	I _{EE}		150	175	mA	No load, over supply voltage		

Note 1: Required 500 lfpm air flow when using +5V or -5V power supply.

LVPECL DC ELECTRICAL CHARACTERISTICS (100KEP)

Electrical Characteristics: V _{CC} = 3.3V, V _{EE} = 0V; T _A = -40°C to +85°C. (Note 1, Note 2)								
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions		
Output High Voltage	V _{OH}	2155	2280	2405	mV	Figure 7-1, All loading with 50 Ω to $V_{CC} - 2V$		
Output Low Voltage	V _{OL}	1355	1480	1605	mV	Figure 7-1, All loading with 50Ω to $V_{CC} - 2V$		
PECL Input High Voltage		2075	_	2420				
CMOS Input High Voltage	V _{IH}	1815		_	mV	Figure 7-3, Figure 7-4		
TTL Input High Voltage		2000	_	_	1			
PECL Input Low Voltage		1355	_	1675				
CMOS Input Low Voltage	V _{IL}	_	_	1485	mV	Figure 7-3, Figure 7-4		
TTL Input Low Voltage		_	_	800	1			
Output Voltage Reference	V _{BB}	1775	1875	1975	mV	—		
Input Select Voltage	V _{CF}	1610	1720	1825	mV	—		
Mode Connection	V _{EF}	1900	2000	2100	mV	—		
Input High Voltage Common Mode Range (Note 3)	V _{IHCMR}	2.0		3.3	V	Figure 7-6		
Input High Current	I _{IH}			150	μA	—		
Input Low Current		0.5	_		^	IN		
Input Low Current	IL	-150			μA	/IN		

Note 1: Device is guaranteed to meet the DC specifications shown in the table after thermal equilibrium has been established. The device is tested in a socket such that transverse airflow of ≥500 lfpm is maintained.

2: Input and output parameters vary 1:1 with V_{CC}.

3: V_{IHCMR} maximum varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Electrical Characteristics: V _{CC} = 5.0V, V _{EE} = 0V; T _A = -40°C to +85°C. (Note 1, Note 2)								
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions		
Output High Voltage	V _{OH}	3855	3980	4105	mV	Figure 7-1, All loading with 50Ω to $V_{CC} - 2V$		
Output Low Voltage	V _{OL}	3055	3180	3305	mV	Figure 7-1, All loading with 50Ω to $V_{CC} - 2V$		
PECL Input High Voltage		3775	_	4120				
CMOS Input High Voltage	V _{IH}	2750	_	_	mV	Figure 7-3, Figure 7-4		
TTL Input High Voltage		2000	_]			
PECL Input Low Voltage		3055	—	3375				
CMOS Input Low Voltage	V _{IL}	_	_	2250	mV	Figure 7-3, Figure 7-4		
TTL Input Low Voltage		—	_	800]			
Output Voltage Reference	V _{BB}	3475	3575	3675	mV	—		
Input High Voltage Common Mode Range (Note 3)	V _{IHCMR}	2.0		5.0	V	Figure 7-6		
Input High Current	I _{IH}	_		150	μA	_		
Input Low Current		0.5				IN		
Input Low Current	IIL	-150		_	μA	/IN		

PECL DC ELECTRICAL CHARACTERISTICS (100KEP)

Note 1: Device is guaranteed to meet the DC specifications shown in the table after thermal equilibrium has been established. The device is tested in a socket such that transverse airflow of ≥500 lfpm is maintained.

2: Input and output parameters vary 1:1 with V_{CC}.

3: V_{IHCMR} maximum varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

NECL DC ELECTRICAL CHARACTERISTICS (100KEP)

Electrical Characteristics: $V_{CC} = 0V$, $V_{EE} = -5.5V$ to $-3.0V$; $T_A = -40^{\circ}C$ to $+85^{\circ}C$.								
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions		
Output High Voltage	V _{OH}	-1145	-1020	-895	mV	Figure 7-2, All loading with 50 Ω to V _{CC} – 2V		
Output Low Voltage	V _{OL}	-1945	-1820	-1695	mV	Figure 7-2, All loading with 50Ω to $V_{CC} - 2V$		
Input High Voltage NECL	V _{IH}	-1225	—	-880	mV	Figure 7-5		
Input Low Voltage NECL	V _{IL}	-1945	—	-1625	mV	Figure 7-5		
Output Voltage Reference	V _{BB}	-1525	-1425	-1325	mV	—		
Input High Voltage Common Mode Range ()	V _{IHCMR}	V _{EE} + 2.0	_	0.0	V	Figure 7-7		
Input High Current	I _{IH}	—	—	150	μA	_		
Input Low Current		0.5	_	_		IN		
	Ι _{ΙL}	-150	—	—	μA	/IN		

Note 1: Device is guaranteed to meet the DC specifications shown in the table after thermal equilibrium has been established. The device is tested in a socket such that transverse airflow of ≥500 lfpm is maintained.

2: V_{IHCMR} minimum varies 1:1 with V_{EE}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

AC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{CC} = 3.0 to 5.5V, V_{EE} = 0V or V_{CC} = 0V, V_{EE} = -3.0 to -5.5V; T_A = -40°C to +85°C. (Note 1, Note 2)

(Note 1, Note 2)							
Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions	
Maximum Frequency	f _{MAX}	1.6	—		GHz	Note 3	
		1650	2000	2450		$T_A = -40^{\circ}C$	
Propagation Delay, IN-to-Q; D[0-9] = 0		1800	2070	2600	ps	T _A = +25°C	
D[0-0] = 0		1950	2150	2750		T _A = +85°C	
		9500	10551	13500		$T_A = -40^{\circ}C$	
Propagation Delay, IN-to-Q; D[0-9] = 1023		9800	10756	14000	ps	T _A = +25°C	
D[0-9] = 1023		10600	11226	15800		T _A = +85°C	
	t _{PD}	1600	2150	2600		$T_A = -40^{\circ}C$	
Propagation Delay, /EN-to-Q; D[0-9] = 0		1800	2300	2800	ps	T _A = +25°C	
D[0-9] = 0		2000	2430	3000		T _A = +85°C	
		300	400	500		$T_A = -40^{\circ}C$	
Propagation Delay, D10 to CASCADE		325	410	550	ps	T _A = +25°C	
CASCADE		325	430	625		T _A = +85°C	
		7850	8551	_		$t_{PD(MAX)} - t_{PD(MIN)}, T_A = -40^{\circ}C$	
Programmable Range	t _{RANGE}	8000	8686	_	ps	$t_{PD(MAX)} - t_{PD(MIN)}, T_A = +25^{\circ}C$	
		8650	9076	_		$t_{PD(MAX)} - t_{PD(MIN)}, T_A = +85^{\circ}C$	
Step Delay, D0 High		_	9	_	ps	$T_A = -40^{\circ}C$	
Note 4 applies to all Step Delay		_	10	_		T _A = +25°C	
entries.			10			T _A = +85°C	
Step Delay, D1 High			25	_	ps	$T_A = -40^{\circ}C$	
		_	26	_		T _A = +25°C	
			27			T _A = +85°C	
			42			$T_A = -40^{\circ}C$	
Step Delay, D2 High		_	42	_	ps	T _A = +25°C	
			43			T _A = +85°C	
		_	75	_		$T_A = -40^{\circ}C$	
Step Delay, D3 High		_	80	_	ps	T _A = +25°C	
	٨+	_	81	_		T _A = +85°C	
	Δt	_	142	_		$T_A = -40^{\circ}C$	
Step Delay, D4 High		_	143	_	ps	T _A = +25°C	
		_	150	_		T _A = +85°C	
		_	296	_		$T_A = -40^{\circ}C$	
Step Delay, D5 High		_	300	_	ps	T _A = +25°C	
			310			T _A = +85°C	
			532			$T_A = -40^{\circ}C$	
Step Delay, D6 High			540	_	ps	T _A = +25°C	
			565	_		T _A = +85°C	
	1		1080			$T_A = -40^{\circ}C$	
Step Delay, D7 High			1095		ps	T _A = +25°C	
		_	1140	_		T _A = +85°C	

AC ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{CC} = 3.0 to 5.5V, V_{EE} = 0V or V_{CC} = 0V, V_{EE} = -3.0 to -5.5V; T_A = -40°C to +85°C. (Note 1, Note 2)

(Note 1, Note 2) Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
i ulunotoi	- Cymson		-			
Stan Doloy, D9 High			2100			$T_{A} = -40^{\circ}C$
Step Delay, D8 High			2150		ps	$T_{A} = +25^{\circ}C$
	Δt		2250			$T_{A} = +85^{\circ}C$
Stan Dalay, DO Llink			4250			$T_{A} = -40^{\circ}C$
Step Delay, D9 High			4300		ps	$T_{A} = +25^{\circ}C$
			4500			$T_A = +85^{\circ}C$
Duty Cycle Skew, t _{PHL} – t _{PLH}	t _{SKEW}	_	25		ps	T _A = +25°C, Note 5
Setup Time, D-to-LEN		200	0	—	ps	—
		300	140			$T_A = -40^{\circ}C$
Setup Time, D-to-IN (Note 6)		300	160		ps	$T_A = +25^{\circ}C$
	t _S	300	180			T _A = +85°C
		300	150	—	ps	$T_A = -40^{\circ}C$
Setup Time, /EN-to-IN (Note 7)		300	170	—		T _A = +25°C
		300	180	_		T _A = +85°C
		200	60	_	ps	$T_A = -40^{\circ}C$
Hold Time, LEN-to-D		200	100			T _A = +25°C
		200	80			T _A = +85°C
	t _H	400	250	_		$T_A = -40^{\circ}C$
Hold Time, IN-to-/EN (Note 8)		400	280		ps	T _A = +25°C
		400	300	_		T _A = +85°C
Release Time, /EN-to-IN (Note 9)			500		ps	T _A = +25°C
		400	200	_		$T_A = -40^{\circ}C$
Release Time,		400	250		ps	$T_A = +25^{\circ}C$
SETMAX-to-LEN	t _R	400	300	_		$T_A = +85^{\circ}C$
		350	275			$T_A = -40^{\circ}C$
Release Time, SETMIN-to-LEN		350	200		ps	T _A = +25°C
		350	335			T _A = +85°C

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AC ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: $V_{CC} = 3.0$ to 5.5V, $V_{EE} = 0V$ or $V_{CC} = 0V$, $V_{EE} = -3.0$ to -5.5V; $T_A = -40^{\circ}C$ to $+85^{\circ}C$. (Note 1, Note 2)

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Cycle-to-Cycle Jitter	t _{JIT}		0.2	<1	ps _{RMS}	Note 10
Input Voltage Swing (Differential)	V _{PP}	150	800	1200	mV	_
	—			150		$T_A = -40^{\circ}C$
Output Rise/Fall Time, 20% to 80% (Q)		—	—	150	ps	T _A = +25°C
	+ /+	—	—	175		T _A = +85°C
	- t _r /t _f		180	250		$T_A = -40^{\circ}C$
Output Rise/Fall Time, 20% to 80% (CASCADE)		_	210	300	ps	T _A = +25°C
		_	230	325		T _A = +85°C

Note 1: AC characteristics are guaranteed by design and characterization.

- 2: Measured using 750 mV source, 50% duty cycle clock source, $R_L = 50\Omega$ to $V_{CC} 2V$.
- 3: Refer to Typical Operating Characteristics section for output swing performance.
- 4: The delays of the individual bits are cumulative.
- **5:** Duty cycle skew guaranteed only for differential operation measured from the crosspoint of the input edge to the crosspoint of the corresponding output edge.
- 6: Setup time defines the amount of time prior to an edge on IN, /IN that the D[0:9] bits must be set to guarantee the new delay will occur for that edge.
- 7: Setup time is the minimum that /EN must be asserted prior to the next transition of IN, /IN to prevent an output response greater than ±75 mV to that IN, /IN transition.
- 8: Hold time is the minimum time that /EN must remain asserted after a negative-going IN or a positive-going /IN to prevent an output response greater than ±75 mV to that IN, /IN transition.
- **9:** Release time is the minimum time that /EN must be deasserted prior to the next IN, /IN transition to ensure an output response that meets the specified IN-to-Q propagation delay and transition times.
- **10:** This is the amount of generated jitter added to an otherwise jitter-free clock signal, going from IN, /IN-to-Q, /Q.

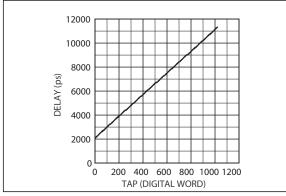
TEMPERATURE SPECIFICATIONS

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Temperature Ranges							
Ambient Temperature Range	T _A	-40	_	+85	°C	—	
Storage Temperature Range	Τ _S	-65	_	+150	°C	—	
Lead Temperature	_	_	_	+260	°C	Soldering, 20s	
Package Thermal Resistances	Package Thermal Resistances						
32-lead TQFP (Still-Air)	θ _{JA}	_	50	_	°C/W	_	
32-lead TQFP (500 lfpm)	θ _{JA}	_	42	_	°C/W	—	
32-lead TQFP	θ _{JC}		20		°C/W	—	

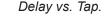
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2.0 **TYPICAL PERFORMANCE CURVES**

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.







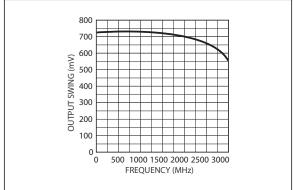
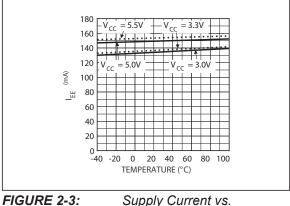


FIGURE 2-2: Q, /Q Output Swing vs. Frequency.



Temperature.

Supply Current vs.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1:		
Pin Number	Pin Name	Description
23, 25, 26, 27, 29, 30, 31, 32, 1, 2	D[0:9]	CMOS, ECL, or TTL Select Inputs: These digital control signals adjust the amount of delay from IN-to-Q. Please refer to the AC Electrical Characteristics and Table 5-1 for delay values. Figure 8-4 through Figure 8-8 show how to interface these inputs to various logic family standards. These inputs default to logic low when left unconnected. Bit 0 is the least significant bit, and bit 9 is the most significant bit
3	D[10]	CMOS, ECL, or TTL Select Input: This input latches just like D[0:9] does. It drives the CASCADE, /CASCADE differential pair. Use only when cascading two or more SY100EP195V to extend the range of delays required.
4, 5	IN, /IN	ECL Input: This is the signal to be delayed. If this input pair is left unconnected, this is equivalent to a logic low input.
6	VBB	Voltage Output: When using a single-ended logic source for IN and /IN, connect the unused input of the differential pair to this pin. This pin can also re-bias AC-coupled inputs to IN and /IN. When used, de-couple this pin to V_{CC} through an 0.01 μ F capacitor. Limit current sinking or sourcing to 0.5 mA or less.
7	VEF	Voltage Output: Connect this pin to VCF when the D inputs are ECL. Refer to the Digital Control Logic Standard section of the Functional Description to interface the D inputs to CMOS or TTL.
8	VCF	Voltage Input: The voltage at this pin sets the logic transition threshold for the D inputs.
9, 24, 28	VEE	Most Negative Supply: Supply ground for PECL systems.
10	LEN	ECL Control Input: When logic low, the D inputs flow through. Any changes to the D inputs reflect in the delay between IN, /IN and Q, /Q. When logic high, the logic values at D are latched, and these latched bits determine the delay.
11	SETMIN	ECL Control Input: When logic high, the contents of the D register are reset. This sets the delay to the minimum possible, equivalent to D[0:9] being set to 000000000. When logic low, the value of the D register, or the logic value of SETMAX determines the delay from IN, /IN to Q, /Q. This input defaults to logic low when left unconnected.
12	SETMAX	ECL Control Input: When logic high and SETMIN is logic low, the contents of the D register are set high, and the delay is set to one step greater than the maximum possible with D[0:9] set to 111111111. When logic low, the value of the D register, or the logic value of SETMIN determines the delay from IN, /IN to Q, /Q. This input defaults to logic low when left unconnected.
13, 18, 19, 22	VCC	Most Positive Supply: Supply ground for NECL systems. Bypass to V_{EE} with 0.1 μF and 0.01 μF low-ESR capacitors.
15, 14	CASCADE, /CASCADE	100K ECL Outputs: These outputs are used when cascading two or more SY100EP195V to extend the delay range required.
16	/EN	ECL Control Input: When set active low, Q, /Q are a delayed version of IN, /IN. When set inactive high, IN, /IN are gated such that Q, /Q become a differential logic low. This input defaults to logic low when left unconnected.
21, 20	Q, /Q	100K ECL Outputs: This signal pair is the delayed version of IN, /IN.
17	NC	No Connect: Leave this pin unconnected.

TABLE 3-1:PIN FUNCTION TABLE

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4.0 FUNCTIONAL DESCRIPTION

SY100EP195V is a programmable delay line, varying the delay of a PECL or NECL input signal by any amount between about 2.1 ns and 10.8 ns. A 10-bit digital control register affords delay steps of approximately 10 ps.

SY100EP195V implements the delay using a multiplexer chain and a set of fixed delay elements. Under digital control, various subsets of the delay elements are included in the signal chain. To simplify interfacing, the 10-bit digital delay control word interfaces to PECL, CMOS, or TTL interface standards.

Because multiplexers must appear in the delay path, SY100EP195V has a minimum delay of about 2.1 ns. Delays below this value are not possible. In addition, when cascading multiple SY100EP195V to extend the delay range, the minimum delay is about 2.1 ns multiplied by the number of SY100EP195V in cascade. An eleventh control bit, D[10], along with the CASCADE and /CASCADE outputs and the SETMIN and SETMAX inputs, simplifies the task of cascading.

4.1 Signal Path Logic Standard

The signal path, from IN, /IN to Q, /Q, interfaces to PECL, LVPECL, or NECL signals, as shown in Table 4-6. The choice of signal path logic standard may limit possible choices for the delay control inputs, D.

4.2 Input Enable

The /EN input gates the signal at IN, /IN. When disabled, the input is effectively gated out, just as if a logic low was being provided to SY100EP195V.

TABLE 4-1:/EN TRUTH TABLE

/EN	Value at Q, /Q				
L	IN, /IN Delayed				
Н	Logic Low Delayed				

4.3 Digital Control Latch

SY100EP195V can capture the digital delay control word into its internal 11-bit latch, 10 bits for D[0:9], and an extra bit for the D[10] cascade control. The LEN input controls the action of this latch, as per Table 4-2.

Note that the LEN input is always PECL, LVPECL, or NECL, the same as the IN, /IN signal pair. The 11-bit delay control word, however, may also be CMOS or TTL.

TABLE 4-2:LEN TRUTH TABLE

LEN	Latch Action			
L	Pass Through D[0:10]			
Н	Latch D[0:10]			

The nominal delay value is based on the binary value in D[0:9], where D[0] is the least significant bit, and D[9] is the most significant bit.

4.4 Digital Control Logic Standard

When used in systems where VEE connects to ground, SY100EP195V may interface either to PECL, CMOS, or TTL on its D[0:10] inputs. To this end, the VCF pin sets the threshold at which the D inputs switch between logic low and logic high.

As shown in Table 4-3, connecting VCF to VEF sets the threshold to PECL (if V_{CC} is 5V) or LVPECL (if V_{CC} is 3.3V). Leaving VCF and VEF open yields a threshold suitable for detecting CMOS output logic levels. Leaving VEF open and connecting VCF to a 1.5V source allows the D inputs to accept TTL signals.

TABLE 4-3:DIGITAL CONTROLSTANDARD TRUTH TABLE

Logic Standard	VCF Connection				
ECL, PECL	VEF				
CMOS	No Connect				
TTL	1.5V Source				

If a 1.5V source is not available, connecting VCF to VEE through an appropriate resistor will bias VCF at about 1.5V. The value of this resistor depends on the V_{CC} supply, as indicated in Table 4-4.

TABLE 4-4: RESISTOR VALUES FOR TTL INPUT

V _{cc}	Resistor Value
3.3V	1.5 kΩ
5.0V	500Ω

4.5 Cascade Logic

SY100EP195V is designed to ease cascading multiple devices in order to achieve a greater delay range. The SETMIN and SETMAX pins accomplish this, as set out in the applications section below. SETMIN and SETMAX override the delay by changing the value in the D latch register. Table 4-5 lists the action of these pins.

TABLE 4-5: SETMIN & SETMAX ACTION

SETMIN	SETMAX	Nominal Delay (ps)		
L	L	As per D Latch		
L	Н	2100 + 8686		
Н	L	2100		
Н	Н	Not Allowed		

Logic	V _{cc}	V _{EE}	Delay Control Input Choices
PECL	+4.5V to +5.5V	0V	PECL, CMOS, TTL
LVPECL	+3.0V to +3.6V	0V	LVPECL, CMOS, TTL
NECL	0V	-3.0V to -5.5V	NECL

TABLE 4-6: SIGNAL PATH LOGIC STANDARD

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5.0 APPLICATION INFORMATION

For best performance, use good high frequency layout techniques, filter V_{CC} supplies, and keep ground connections short. Use multiple vias where possible. Also, use controlled impedance transmission lines to interface with the SY100EP195V data inputs and outputs.

5.1 V_{BB} Supply

The VBB pin is an internally generated supply, and is available for use only by the SY100EP195V. When unused, this pin should be left unconnected. The two common uses for VBB are to handle a single-ended PECL input, and to re-bias inputs for AC-coupling applications.

If IN, /IN is driven by a single-ended output, VBB is used to bias the unused input. Please refer to Figure 8-1. The PECL signal driving SY100EP195V may optionally be inverted in this case.

When the signal is AC-coupled, VBB is used, as shown in Figure 8-3, to re-bias IN, /IN. This ensures that SY100EP195V inputs are within its acceptable common mode range.

In all cases, VBB current sinking our sourcing must be limited to 0.5 mA or less.

5.2 Setting D Input Logic Thresholds

In all designs where the SY100EP195V V_{EE} supply is at zero volts, the D inputs may accommodate CMOS and TTL level signals, as well as PECL or LVPECL. Figure 8-4 through Figure 8-8 show how to connect VCF and VEF for all possible cases.

5.3 Cascading

Two or more SY100EP195V may be cascaded, in order to extend the range of delays permitted. Each additional SY100EP195V adds about 2100 ps to the minimum delay, and adds another 8686 ps to the delay range.

Internal cascade circuitry has been included in the SY100EP195V. Using this internal circuitry, SY100EP195V may be cascaded without any external gating.

Examples of cascading 2, 3, or 4 SY100EP195V appear in Figure 5-1, Figure 5-2, and Figure 5-3. Table 5-1 lists the nominal delay for all the cases that appear in those figures.

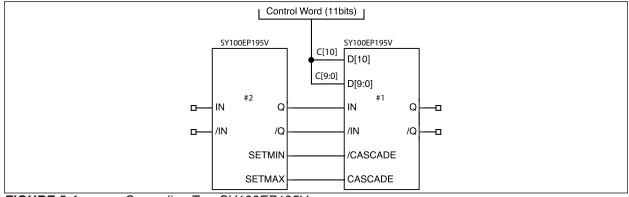
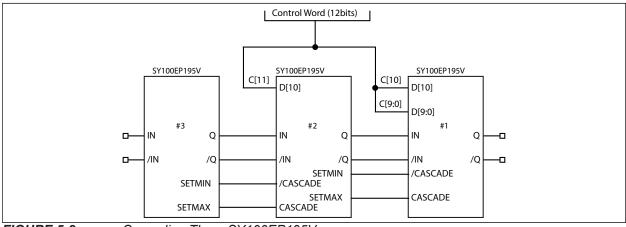


FIGURE 5-1: Cascading Two SY100EP195V.





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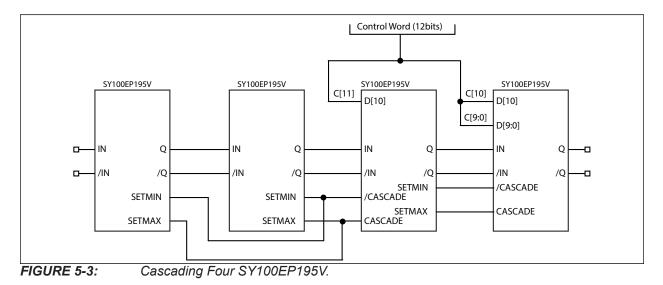


TABLE 5-1: NOMINAL DELAY VALUES FOR CASCADED SY100EP195V

	Control Input	S	Nominal Delay (ps)				
D[11]	D[10]	D[9:0]	One Chip	Two Chips	Three Chips	Four Chips	
0	0	000000000	2070	4140	6210	8280	
0	0	000000001	2080	4150	6220	8290	
0	0	000000010	2096	4166	6236	8306	
0	0	000000100	2112	4182	6252	8322	
0	0	0000001000	2150	4220	6290	8360	
0	0	0000010000	2213	4283	6353	8423	
0	0	0000100000	2370	4440	6510	8580	
0	0	0001000000	2610	4680	6750	8820	
0	0	001000000	3165	5235	7305	9375	
0	0	010000000	4220	6290	8360	10430	
0	0	100000000	6370	8440	10510	12580	
0	0	111111111	10756	12826	14896	16966	
0	1	000000000		12836	14906	16976	
0	1	000000001		12846	14916	16986	
0	1	000000010		12862	14932	17002	
0	1	000000100		12878	14948	17018	
0	1	0000001000		12916	14986	17056	
0	1	0000010000		12979	15049	17119	
0	1	0000100000		13136	15206	17276	
0	1	0001000000		13376	15446	17516	
0	1	001000000		13931	16001	18071	
0	1	010000000		14986	17056	19126	
0	1	100000000	_	17136	19206	21276	
0	1	111111111		21522	23592	25662	
1	0	000000000		—	14906	25672	
1	0	000000001		_	14916	25682	
1	0	000000010		_	14932	25698	
1	0	000000100		—	14948	25714	

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						,	
Control Inputs			Nominal Delay (ps)				
D[11]	D[10]	D[9:0]	One Chip	Two Chips	Three Chips	Four Chips	
1	0	0000001000		_	14986	25752	
1	0	0000010000		_	15049	25815	
1	0	0000100000		_	15206	25972	
1	0	0001000000		_	15446	26212	
1	0	001000000		_	16001	26767	
1	0	010000000		_	17056	27822	
1	0	100000000		_	19206	29972	
1	0	1111111111		_	23592	34358	
1	1	0000000000			23602	34368	
1	1	000000001		_	23612	34378	
1	1	000000010		_	23628	34394	
1	1	000000100			23644	34410	
1	1	0000001000		_	23682	34448	
1	1	0000010000		_	23745	34511	
1	1	0000100000		_	23902	34668	
1	1	0001000000		_	24142	34908	
1	1	001000000		_	24797	35563	
1	1	010000000		_	25752	36518	
1	1	100000000		_	27902	38668	
1	1	1111111111		_	32288	43054	

TABLE 5-1: NOMINAL DELAY VALUES FOR CASCADED SY100EP195V (CONTINUED)

6.0 **INPUT AND OUTPUT STRUCTURES**

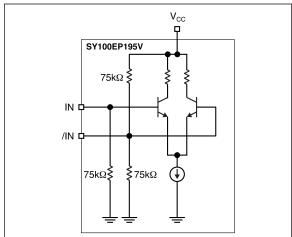


FIGURE 6-1:

Differential Input Structure.

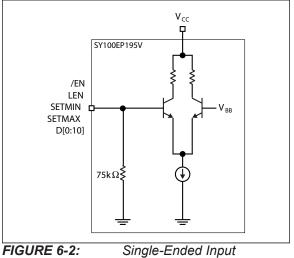
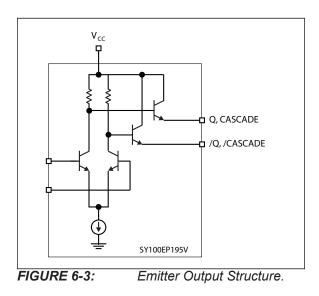
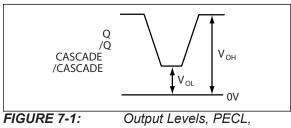


FIGURE 6-2: Structure.



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7.0 INPUT AND OUTPUT LEVELS



LVPECL.

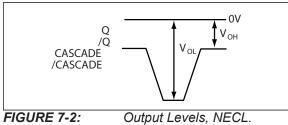


FIGURE 7-2:

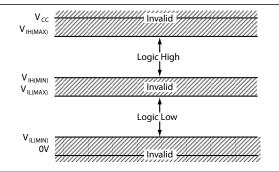
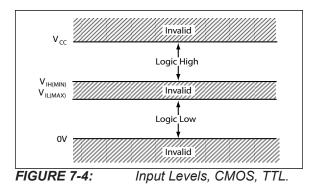


FIGURE 7-3: Input Levels, PECL.



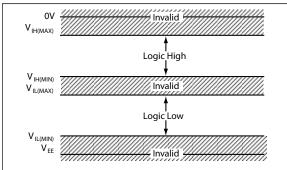


FIGURE 7-5: Input Levels, NECL.

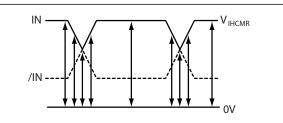


FIGURE 7-6: Input Common Mode, PECL, LVPECL.

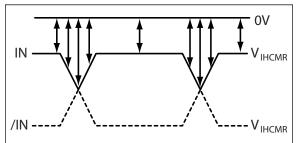
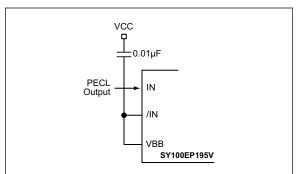


FIGURE 7-7: Input Common Mode, NECL.

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8.0 INPUT INTERFACE APPLICATIONS





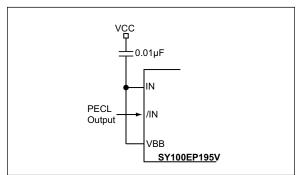
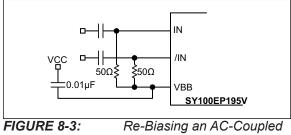
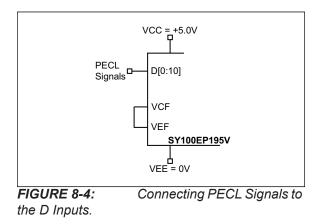
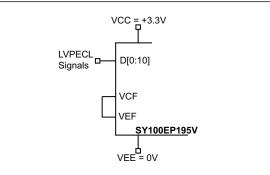


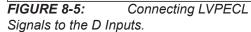
FIGURE 8-2: Interfacing to an Inverting Single-Ended PECL Signal.

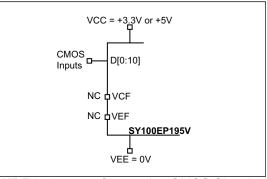


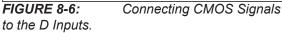












Note: V_{CF} and V_{EF} are not connected.

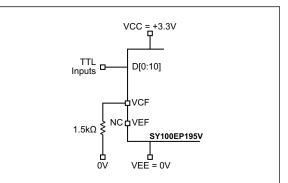


FIGURE 8-7: Connecting TTL Signals to the D Inputs with $V_{CC} = 3.3V$.

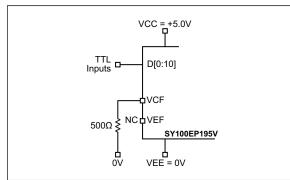


FIGURE 8-8: Connecting TTL Signals to the D Inputs with $V_{CC} = 5.0V$.

9.0 OUTPUT PECL TERMINATION

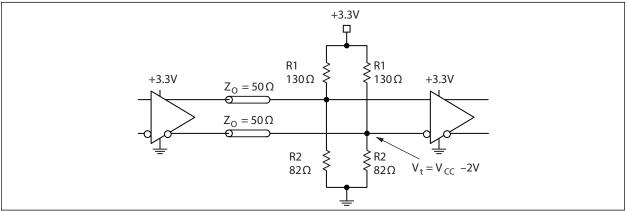


FIGURE 9-1:Parallel Termination – Thevenin Equivalent.Note:For +5.0V systems: R1 = 82Ω, R2 = 130Ω.

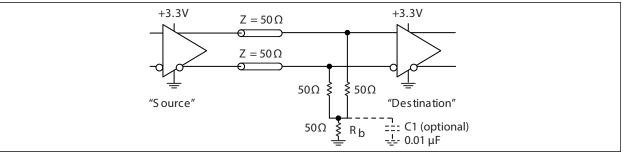


FIGURE 9-2: Three-Resistor "Y-Termination".

Note: Power-saving alternative to Thevenin termination.

Note: Place termination resistors as close to destination inputs as possible.

Note: R_b resistor set the DC bias voltage, equal to V_T. For +3.3V systems, R_b = 46 Ω to 50 Ω . For +5V systems, R_b = 110 Ω .

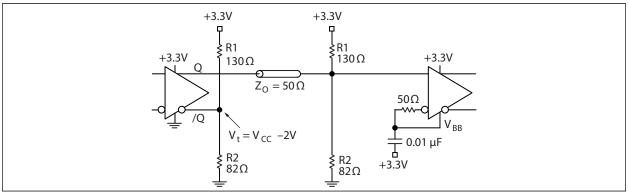


FIGURE 9-3: Terminating Unused I/O.

Note: Unused output (/Q) must be terminated to balance the output.

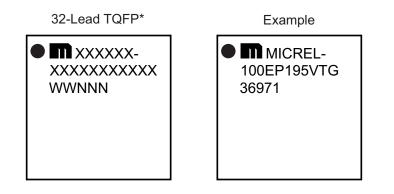
Note: Microchip's differential I/O logic devices include a V_{BB} reference pin.

Note: Connect unused input through 50 Ω to V_{BB}. Bypass with a 0.01 µF capacitor to V_{CC}, not GND, because PECL is referenced to V_{CC}.

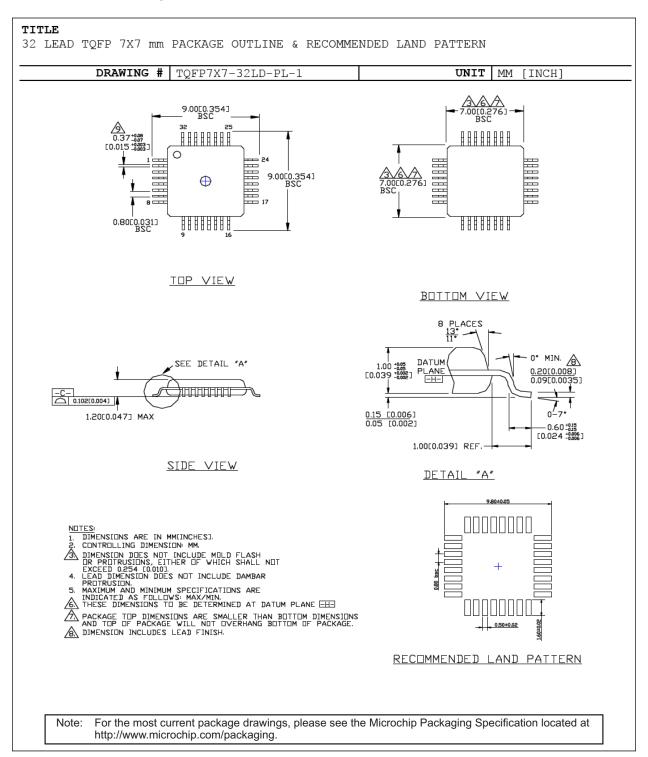
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10.0 PACKAGING INFORMATION

10.1 Package Marking Information



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be carried characters the corpor	At the full Microchip part number cannot be marked on one line, it will a over to the next line, thus limiting the number of available for customer-specific information. Package may or may not include ate logo. (_) and/or Overbar (⁻) symbol may not be to scale.
	Y YY WW NNN @3 * •, ▲, ▼ mark). In the ever the carried characters the corpora



32-Lead TQFP Package Outline and Recommended Land Pattern

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NOTES:

APPENDIX A: REVISION HISTORY

Revision A (May 2019)

- Converted Micrel document SY100EP195V to Microchip data sheet DS20006194A.
- Minor text changes throughout.
- Recalculated value updates to AC Electrical Characteristics and Table 5-1.

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NOTES:

PRODUCT IDENTIFICATION SYSTEM

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PART NO. X X X XX				Exa	Examples:			
⊺ Voltage		x nperature	T	a)	SY	100EP195VTG:	SY100EP195, 3.3V to 5V Voltage Option, 32-Lead TQFP, -40°C to +85°C Temp. Range, 250/Tray	
SY100EF	2195: 3.3V/5V	1.6 GHz Pro	ogrammable Delay	b)	SY	100EP195VTG-TR:	SY100EP195, 3.3V to 5V Voltage Option, 32-Lead TQFP, -40°C to +85°C	
V =	3.3V to 5.5V						Temp. Range, 1,000/Reel	
T =	32-Lead 7 mm	x 7 mm TQ	FP	Not	. 1.	Topo and Pool idar	tifier only opposed in the	
G =	–40°C to +85°C	2			÷ I.	catalog part numbe used for ordering p the device package	er description. This identifier is urposes and is not printed on e. Check with your Microchip	
Blank = TR =	250/Tray 1,000/Reel					Sales Office for page Tape and Reel opti	ckage availability with the on.	
	Voltage Option SY100EF V = T = G = Blank =	Voltage Package Ten Option SY100EP195: $3.3V/5V$ V = $3.3V$ to $5.5V$ T = 32 -Lead 7 mm G = -40° C to $+85^{\circ}$ C Blank = $250/Tray$	Voltage Package Temperature Option SY100EP195: $3.3V/5V 1.6 \text{ GHz Pr}$ V = 3.3V to 5.5V T = 32-Lead 7 mm x 7 mm TQ $G = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ Blank = 250/Tray	Voltage OptionPackage Temperature Media TypeSY100EP195: $3.3V/5V$ 1.6 GHz Programmable DelayV= $3.3V$ to $5.5V$ T= 32 -Lead 7 mm x 7 mm TQFPG= -40° C to $+85^{\circ}$ CBlank = $250/Tray$	XXXXXVoltage Package TemperatureMedia TypeSY100EP195: $3.3V/5V 1.6 \text{ GHz Programmable Delay}$ b)V= $3.3V \text{ to } 5.5V$ TT= $32\text{-Lead 7 mm x 7 mm TQFP}$ NoteG= $-40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$ NoteBlank = $250/\text{Tray}$ 1	XXXXVoltage Package TemperatureMedia TypeSY100EP195: $3.3V/5V 1.6 \text{ GHz Programmable Delay}$ V= $3.3V to 5.5V$ T= $3.2V to 5.5V$ Blank =250/Tray	X X XX XX Voltage Package Temperature Media Option Image: Additional option Addition Addition	

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